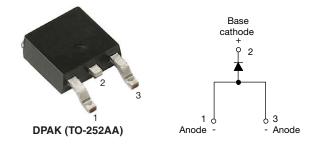


Vishay Semiconductors

High Voltage Surface Mountable Input Rectifier Diode, 8 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	8 A			
V _R	800 V, 1200 V			
V _F at I _F	1.1 V			
I _{FSM}	150 A			
T _J max.	150 °C			
Package	DPAK (TO-252AA)			
Circuit configuration	Single			

FEATURES

- · Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

APPLICATIONS

- Input rectification
- · Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-8EWS..S-M3 rectifier high voltage series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

The high reverse voltage range available allows design of input stage primary rectification with outstanding voltage surge capability.

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 $\mu m)$ copper	1.2	1.6		
Aluminum IMS, R _{thCA} = 15 °C/W	2.5	2.8	A	
Aluminum IMS with heatsink, R_{thCA} = 5 °C/W	5.5	6.5		

Note

• T_A = 55 °C, T_J = 125 °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Sinusoidal waveform	8	А	
V _{RRM}		800/1200	V	
I _{FSM}		150	А	
V _F	8 A, T _J = 25 °C	1.10	V	
TJ		-55 to +150	°C	

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-8EWS08S-M3	800	900	0.5		
VS-8EWS12S-M3	1200	1300	0.5		

Revision: 24-Sep-2019



RoHS

COMPLIANT

HALOGEN

FREE



VS-8EWS08S-M3, VS-8EWS12S-M3

www.vishay.com

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T_C = 105 °C, 180° conduction half sine wave	8	
Maximum peak one cycle non-repetitive surge current	10 ms sine pulse, rated V _{RRM} applied	125	A	
	10 ms sine pulse, no voltage reapplied	150		
Maximum I ² t for fusing I ²	l ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s
	1-1	10 ms sine pulse, no voltage reapplied	110	A-5
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied 1100 A		A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum forward voltage drop	V _{FM}	8 A, T _J = 25 °C		1.1	V
Forward slope resistance	r _t	- T _J = 150 °C		20	mΩ
Threshold voltage	V _{F(TO)}			0.82	V
Maximum reverse leakage current	1	T _J = 25 °C	V _B = Rated V _{BBM}	0.05	mA
waximum reverse leakage current	IRM	T _J = 150 °C	VR - Haleu VRRM	0.50	ШA

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	C/W
Approximate weight			1	g
Approximate weight			0.03	oz.
Marking davias		Case style DPAK (TO-252AA)	8EW	S08S
Marking device		Case sigle DFAR (10-202AA)		S12S

Note

 $^{(1)}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W

For recommended footprint and soldering techniques refer to application note #AN-994

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



VS-8EWS08S-M3, VS-8EWS12S-M3

Vishay Semiconductors

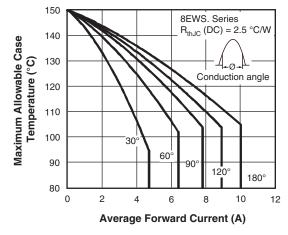


Fig. 1 - Current Rating Characteristics

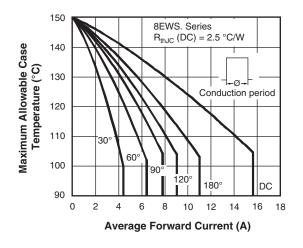


Fig. 2 - Current Rating Characteristics

_____4_{+Ø+}⊢____ Conduction angle

8

10

8EWS. Series

T_J = 150 °C

6

Average Forward Current (A)

Fig. 3 - Forward Power Loss Characteristics

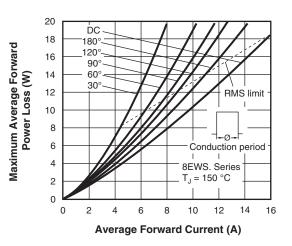
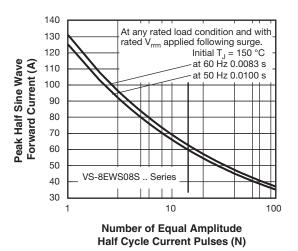


Fig. 4 - Forward Power Loss Characteristics





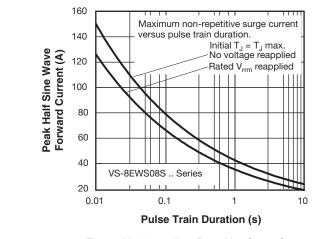


Fig. 6 - Maximum Non-Repetitive Surge Current

Revision: 24-Sep-2019

16

14

12

10

8

6

4

2

0

0

Maximum Average Forward

Power Loss (W)

180°

120

90

60°

30

2

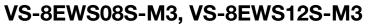
4

RMS limit

Document Number: 93383

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

3



Vishay Semiconductors

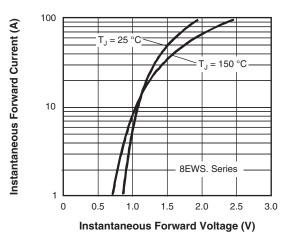


Fig. 7 - Forward Voltage Drop Characteristics

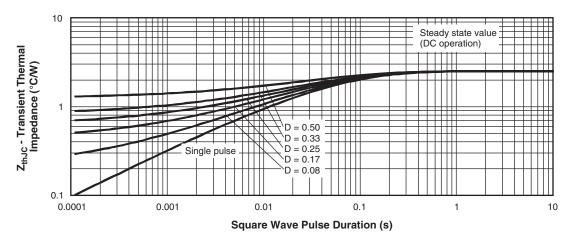


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

Revision: 24-Sep-2019

VISHAY

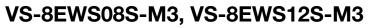
www.vishay.com

Document Number: 93383

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

4

Downloaded from Arrow.com.

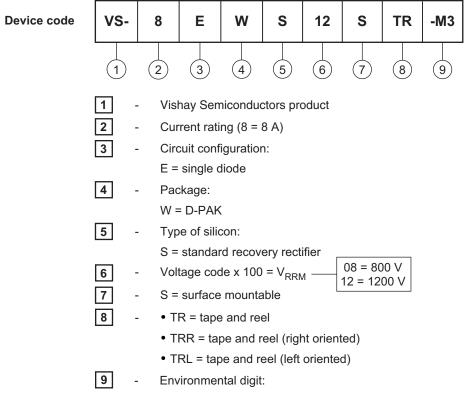


Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

/ISHAY



-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-8EWS08S-M3	75	3000	Antistatic plastic tubes	
VS-8EWS08STR-M3	2000	2000	13" diameter reel	
VS-8EWS08STRL-M3	3000	3000	13" diameter reel	
VS-8EWS08STRR-M3	3000	3000	13" diameter reel	
VS-8EWS12S-M3	75	3000	Antistatic plastic tubes	
VS-8EWS12STR-M3	2000	2000	13" diameter reel	
VS-8EWS12STRL-M3	3000	3000	13" diameter reel	
VS-8EWS12STRR-M3	3000	3000	13" diameter reel	

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95627				
Part marking information	www.vishay.com/doc?95176			
Packaging information	www.vishay.com/doc?95033			
SPICE model	www.vishay.com/doc?96668			

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





www.vishay.com

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.